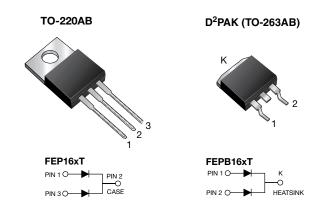


Vishay General Semiconductor

Dual Common Cathode Ultrafast Plastic Rectifier



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LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS							
I _{F(AV)}	2 x 8.0 A						
V_{RRM}	50 V to 600 V						
I _{FSM}	200 A, 125 A						
t _{rr}	35 ns, 50 ns						
V_{F}	0.95 V, 1.30 V, 1.50 V						
T _J max.	150 °C						
Package	TO-220AB, D ² PAK (TO-263AB)						
Circuit configurations Common cathode							

FEATURES

- Power pack
- Glass passivated pellet chip junction



- · Ultrafast recovery time
- · Low switching losses, high efficiency
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 for TO-220AB package
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3 for D²PAK (TO-263AB package)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AB, D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,....)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted)										
PARAMETER	SYMBOL	FEP16AT	FEP16BT	FEP16CT	FEP16DT	FEP16FT	FEP16GT	FEP16HT	FEP16JT	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	500	600	٧
Maximum RMS voltage	V _{RMS}	35	35 70 105 140 210 280				350	420	V	
Maximum DC blocking voltage	V_{DC}	50	50 100 150 200 300 400 500 60					600	V	
Maximum average forward rectified current at T _C = 100 °C	I _{F(AV)}		16							Α
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	200 125							А	
Operating storage and temperature range	T _J , T _{STG}	-55 to +150							°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500							٧	



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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)												
PARAMETER	TEST CONDITIONS		SYMBOL	FEP 16AT	FEP 16BT	FEP 16CT	FEP 16DT	FEP 16FT	FEP 16GT	FEP 16HT	FEP 16JT	UNIT
Maximum instantaneous forward voltage per diode	8.0 A		V _F ⁽¹⁾	0.95			1.30 1.50		50	V		
Maximum DC reverse current per diode at rated DC blocking voltage		$T_C = 25 ^{\circ}C$ $T_C = 100 ^{\circ}C$	I _R	10 500				``				μΑ
Maximum reverse recovery time per diode	$I_F = 0.5 A$ $I_{rr} = 0.25 A$, I _R = 1.0 A, A	t _{rr}		35		5		50		ns	
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	85					6	0	pF	

Note

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THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)									
PARAMETER SYMBOL FEP FEPF FEPB UNIT									
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	2.2	3.1	2.2	°C/W				

ORDERING INFORMATION (Example)									
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
TO-220AB	FEP16JT-E3/45	1.85	45	50/tube	Tube				
TO-263AB	FEPB16JT-E3/45	1.35	45	50/tube	Tube				
TO-263AB	FEPB16JT-E3/81	1.35	81	800/reel	Tape and reel				
TO-220AB	FEP16JTHE3/45 (1)	1.85	45	50/tube	Tube				
TO-263AB	FEPB16JTHE3_A/P (1)	1.35	Р	50/tube	Tube				
TO-263AB	FEPB16JTHE3_A/I (1)	1.35	I	800/reel	Tape and reel				

Note

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽¹⁾ AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

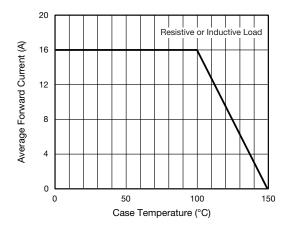


Fig. 1 - Forward Current Derating Curve

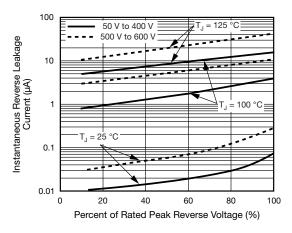


Fig. 4 - Typical Reverse Characteristics Per Diode

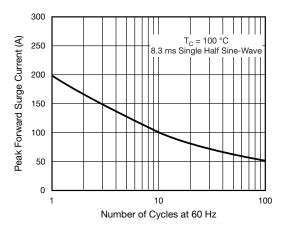


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

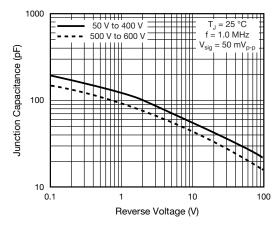


Fig. 5 - Typical Junction Capacitance Per Diode

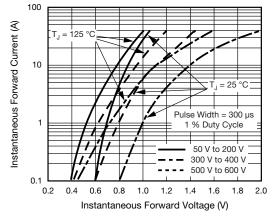
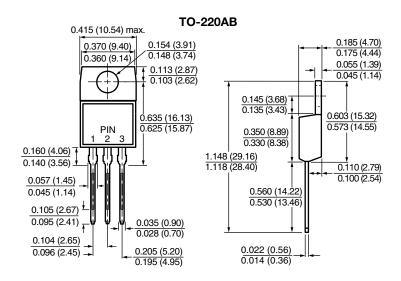


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

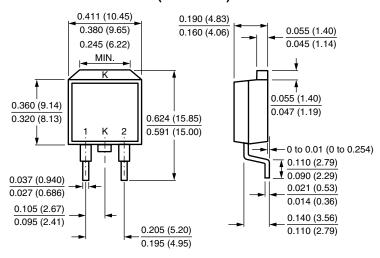


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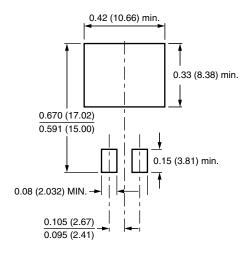
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



D²PAK (TO-263AB)



Mounting Pad Layout





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